

**isc Silicon PNP Darlington Power Transistor**

**BDX88/A/B/C**

**DESCRIPTION**

- High DC Current Gain-  
:  $h_{FE} = 750(\text{Min}) @ I_C = -6A$
- Collector-Emitter Sustaining Voltage-  
:  $V_{CEO(\text{SUS})} = -45V(\text{Min})$ - BDX88;  $-60V(\text{Min})$ - BDX88A  
 $-80V(\text{Min})$ - BDX88B;  $-100V(\text{Min})$ - BDX88C
- Complement to Type BDX87/A/B/C

**APPLICATIONS**

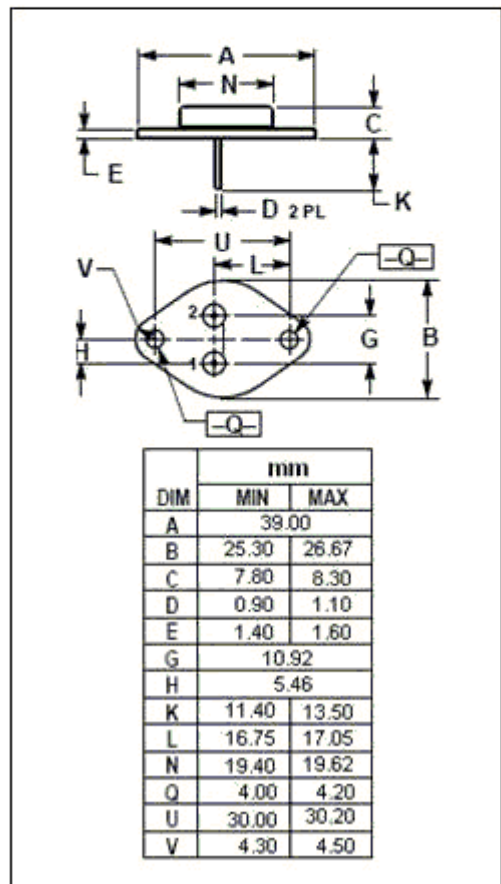
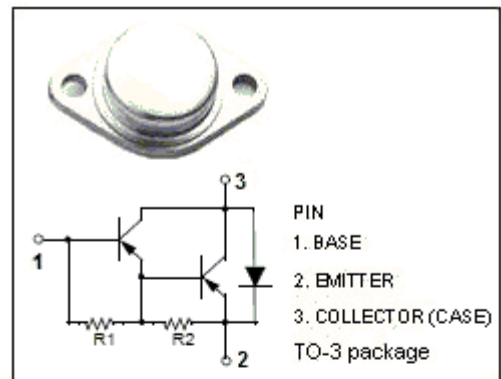
- Designed for use in power linear and switching applications.

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )**

SYMBOL	PARAMETER	VALUE	UNIT	
$V_{CBO}$	Collector-Base Voltage	BDX88	-45	V
		BDX88A	-60	
		BDX88B	-80	
		BDX88C	-100	
$V_{CEO}$	Collector-Emitter Voltage	BDX88	-45	V
		BDX88A	-60	
		BDX88B	-80	
		BDX88C	-100	
$V_{EBO}$	Emitter-Base Voltage	-5	V	
$I_C$	Collector Current-Continuous	-12	A	
$I_{CM}$	Collector Current-Peak	-18	A	
$I_B$	Base Current	-200	mA	
$P_C$	Collector Power Dissipation @ $T_C=25^\circ\text{C}$	120	W	
$T_J$	Junction Temperature	200	$^\circ\text{C}$	
$T_{stg}$	Storage Temperature Range	-65~200	$^\circ\text{C}$	

**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	1.45	$^\circ\text{C/W}$



## isc Silicon PNP Darlington Power Transistor

## BDX88/A/B/C

## ELECTRICAL CHARACTERISTICS

 $T_C=25^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{CEO(SUS)}$	Collector-Emitter Sustaining Voltage	BDX88	$I_C = -100\text{mA}; I_B = 0$	-45			V
		BDX88A		-60			
		BDX88B		-80			
		BDX88C		-100			
$V_{CE(sat)-1}$	Collector-Emitter Saturation Voltage		$I_C = -6\text{A}; I_B = -24\text{mA}$			-2.0	V
$V_{CE(sat)-2}$	Collector-Emitter Saturation Voltage		$I_C = -12\text{A}; I_B = -120\text{mA}$			-3.0	V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage		$I_C = -12\text{A}; I_B = -120\text{mA}$			-4.0	V
$V_{BE(on)}$	Base-Emitter On Voltage		$I_C = -6\text{A}; V_{CE} = -3\text{V}$			-2.8	V
$I_{CBO}$	Collector Cutoff Current	BDX88	$V_{CB} = -45\text{V}; I_E = 0$ $V_{CB} = -45\text{V}; I_E = 0; T_C = 150^\circ\text{C}$			-0.5 -5.0	mA
		BDX88A	$V_{CB} = -60\text{V}; I_E = 0$ $V_{CB} = -60\text{V}; I_E = 0; T_C = 150^\circ\text{C}$			-0.5 -5.0	
		BDX88B	$V_{CB} = -80\text{V}; I_E = 0$ $V_{CB} = -80\text{V}; I_E = 0; T_C = 150^\circ\text{C}$			-0.5 -5.0	
		BDX88C	$V_{CB} = -100\text{V}; I_E = 0$ $V_{CB} = -100\text{V}; I_E = 0; T_C = 150^\circ\text{C}$			-0.5 -5.0	
$I_{CEO}$	Collector Cutoff Current	BDX88	$V_{CE} = -22\text{V}; I_B = 0$			-1.0	mA
		BDX88A	$V_{CE} = -30\text{V}; I_B = 0$				
		BDX88B	$V_{CE} = -40\text{V}; I_B = 0$				
		BDX88C	$V_{CE} = -50\text{V}; I_B = 0$				
$I_{EBO}$	Emitter Cutoff Current		$V_{EB} = -5\text{V}; I_C = 0$			-2.0	mA
$h_{FE-1}$	DC Current Gain		$I_C = -5\text{A}; V_{CE} = -3\text{V}$	1000			
$h_{FE-2}$	DC Current Gain		$I_C = -6\text{A}; V_{CE} = -3\text{V}$	750		18000	
$h_{FE-3}$	DC Current Gain		$I_C = -12\text{A}; V_{CE} = -3\text{V}$	100			